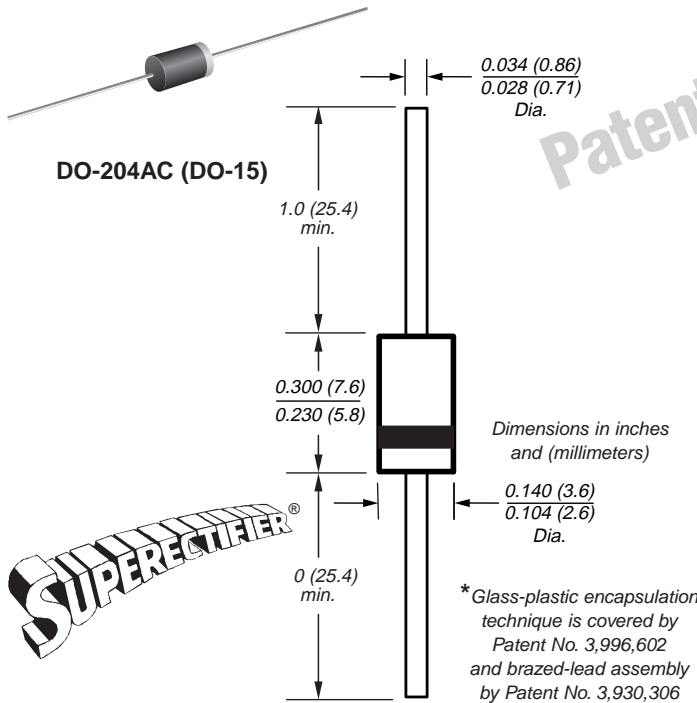




Glass Passivated Junction Rectifiers

Reverse Voltage
200 to 1000V
Forward Current 1.0A



*Patented**

Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- 1.0 Ampere operation at $T_A = 100^\circ\text{C}$ with no thermal runaway
- High temperature soldering guaranteed: $350^\circ\text{C}/10$ seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-204AC, molded plastic over glass body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.015oz., 0.4g

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	1N 4383GP	1N 4384GP	1N 4384GP	1N 4384GP	1N 4384GP	Unit
* Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	V
* Maximum RMS voltage	V _{RMS}	140	280	420	560	700	V
* Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	V
* Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A = 100^\circ\text{C}$	I _{F(AV)}	1.0					A
* Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at $T_A = 100^\circ\text{C}$	I _{FSM}	50					A
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length at $T_A = 100^\circ\text{C}$	I _{R(AV)}	275	250	225	200	200	μA
Typical thermal resistance ⁽¹⁾	R _{θJA}	45					°C/W
* Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175					°C

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Maximum instantaneous forward voltage at 1.0A	V _F	1.0	V
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 150^\circ\text{C}$	I _R	5.0 250	μA
* Typical reverse recovery time at $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$	t _{rr}	2.0	μs
Typical junction capacitance at 4.0V, 1MHz	C _J	15	pF

Note: (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted *JEDEC registered values



Vishay Semiconductors
formerly General Semiconductor

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

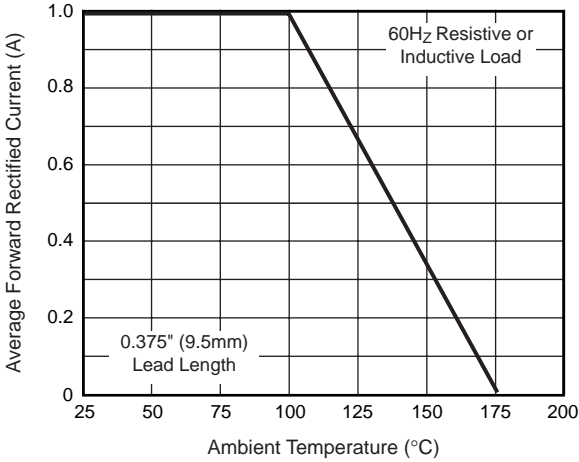


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

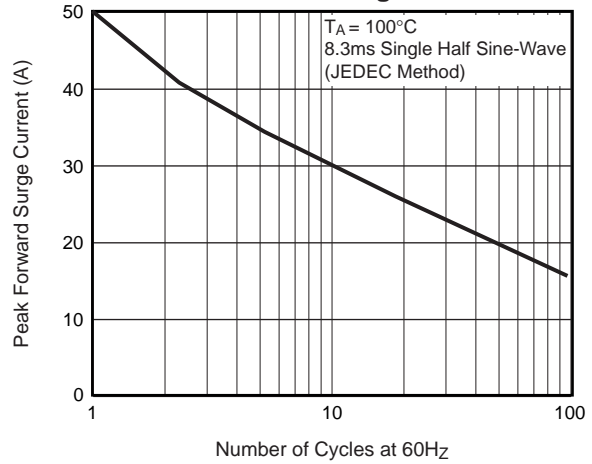


Fig. 3 – Typical Instantaneous Forward Characteristics

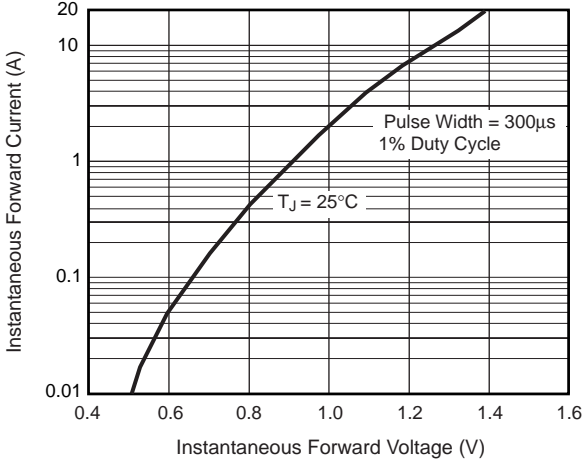


Fig. 4 – Typical Reverse Characteristics

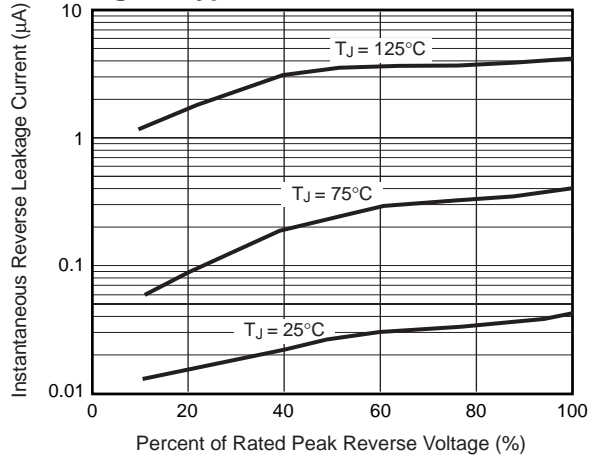


Fig. 5 – Typical Junction Capacitance

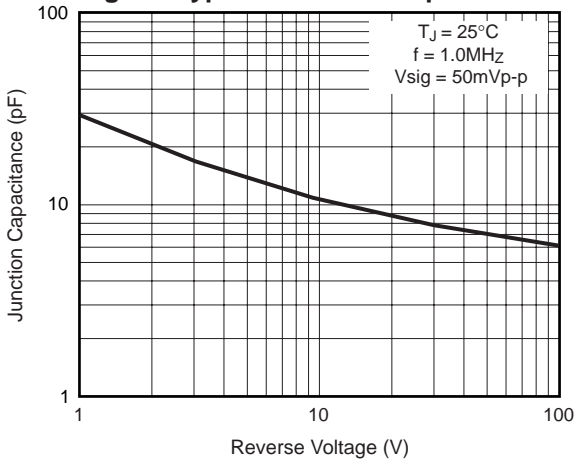


Fig. 6 – Typical Transient Thermal Impedance

